ESA ESTEC
Keplerlaan 1
2201 AZ Noordwijk
The Netherlands

LT1634_TID_TEST_REPORT

LT1634AIS8-2.5#PBF
Date Code: 2101 and 2046
2.5V Bandgap Voltage Reference
Analog Devices

Prepared by Florian Krimmel

Document Type
Reference
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APPROVAL

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CHANGE LOG

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Issue Number	1	Revision Number	0
Reason for change	Date	Pages	Paragraph(s)
Creation	11/05/2022	All	All

DISTRIBUTION

Name/Organisational Unit

Table of Contents

1. INTRODUCTION

The current report presents the TID results on the Bandgap Voltage Reference LT1634

- LT1634AIS8-2.5#PBF, date code: 2101, Analog Devices
- LT1634AIS8-2.5#PBF, date code: 2046, Analog Devices

The test campaign was performed between the 24th January and 18th February 2022 at the ESTEC 60Co facility.

Additional information on the context is provided in the test plan [RD01].

2. DOCUMENTS

2.1. Applicable documents

AD01 ESCC22900 Total Dose Steady-state irradiation test method, June 2016

2.2. Reference documents

RD01 TID_COTS_Bandgap-ref_test_plan

RD02 RA0005344 Radiation Test Summary

3. PART & PROCUREMENT INFORMATION

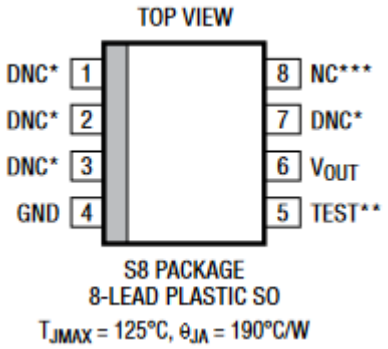
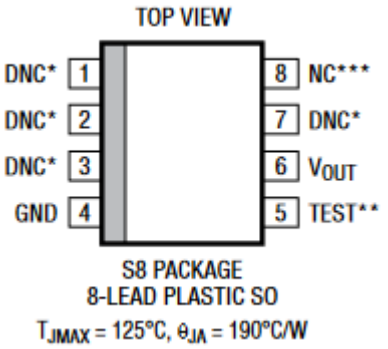
Part number	LT1634AIS8-2.5#PBF	LT1634AIS8-2.5#PBF
Manufacturer	Analog Devices	Analog Devices
Function	2.5V Bandgap Voltage Reference	2.5V Bandgap Voltage Reference
Technology	Bipolar	Bipolar
Package		
Date Code [yyww]	2101	2046
Distributor	Mouser	Mouser
Part # (sample n°) date code	5 samples unbiased (n° C10 to C14) 5 samples biased (n° C15 to C19) 1 reference unbiased (n° REF21) 1 reference biased (n° REF71)	5 samples unbiased (n° C20 to C24) 5 samples biased (n° C25 to C29) 1 reference unbiased (n° REF22) 1 reference biased (n° REF72)

Table 1: Part & procurement information

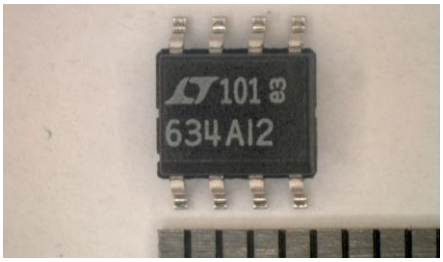
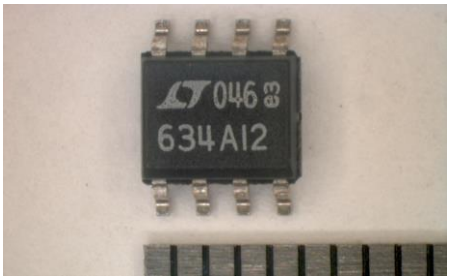
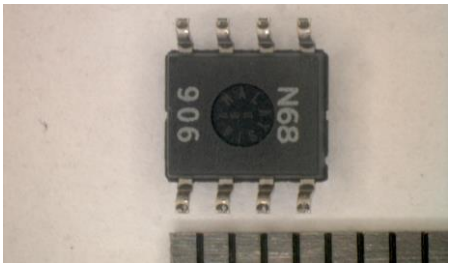
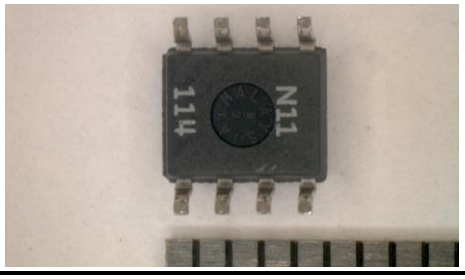
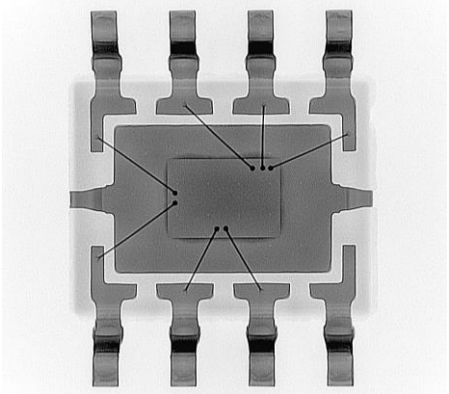
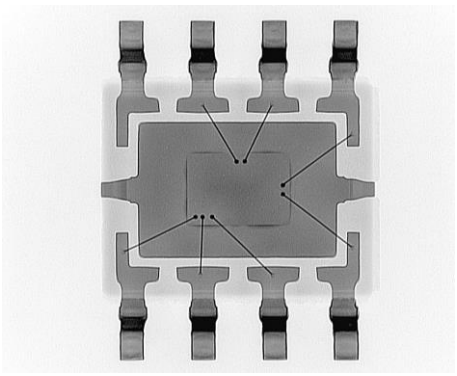
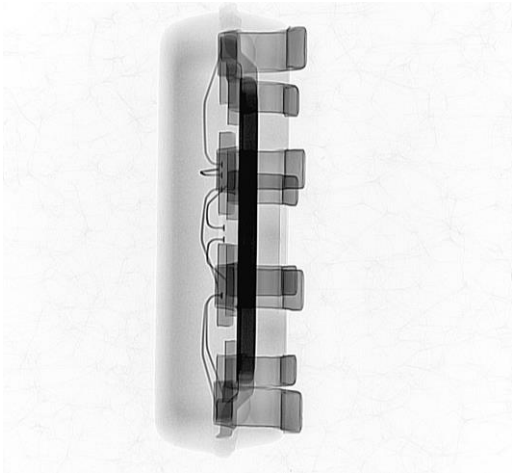
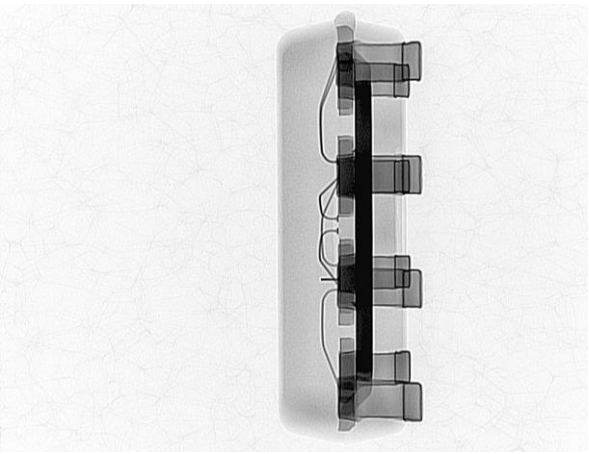
Part number	LT1634AIS8-2.5#PBF	LT1634AIS8-2.5#PBF
Package marking top		
Package marking bottom		
X-ray top view		
X-ray side view		

Table 2: Package marking X-ray of the DUT

4. DOSIMETRY AND IRRADIATION FACILITY

IRRADIATION FACILITY

Source:	C060
Localization:	ESTEC, Netherlands
Dosimetry:	Electrometer: Farmer model 2670 – s/n 491
	Ionisation chamber: PTW TW30012-10 s/n 000417

IRRADIATION TIMING

TID steps (krad(Si))	0, 5, 10, 15, 20, 38.2, 50, 80.5, 100
Dose rate (rad(Si)/h)	240 - 260

ANNEALING TIMING		Condition during annealing
Annealing 22°C	24 h	Biased for those tested biased
		Unbiased for those tested unbiased
Ageing 100°C	168h	ON for those tested ON
		Unbiased for those tested unbiased

Values are provided in TID(H_20), the conversion to TID(Si) is done using the conversion factor of: 0.898.

5. TEST SET-UP

5.1. Test set-up overview

The set-up to measure at specific TID steps outside the irradiation chamber is schematically depicted in the Figure 1. Inside the radiation chamber the component boards with the DUTs on it are connected to the biasing boards which have a determined resistor to create the right value of biasing current (typical current acc. to datasheet) from a 12V supply for each biased component. Additionally to that, there are also 0-Ohm resistors on the biasing boards to connect all pins of the unbiased components.

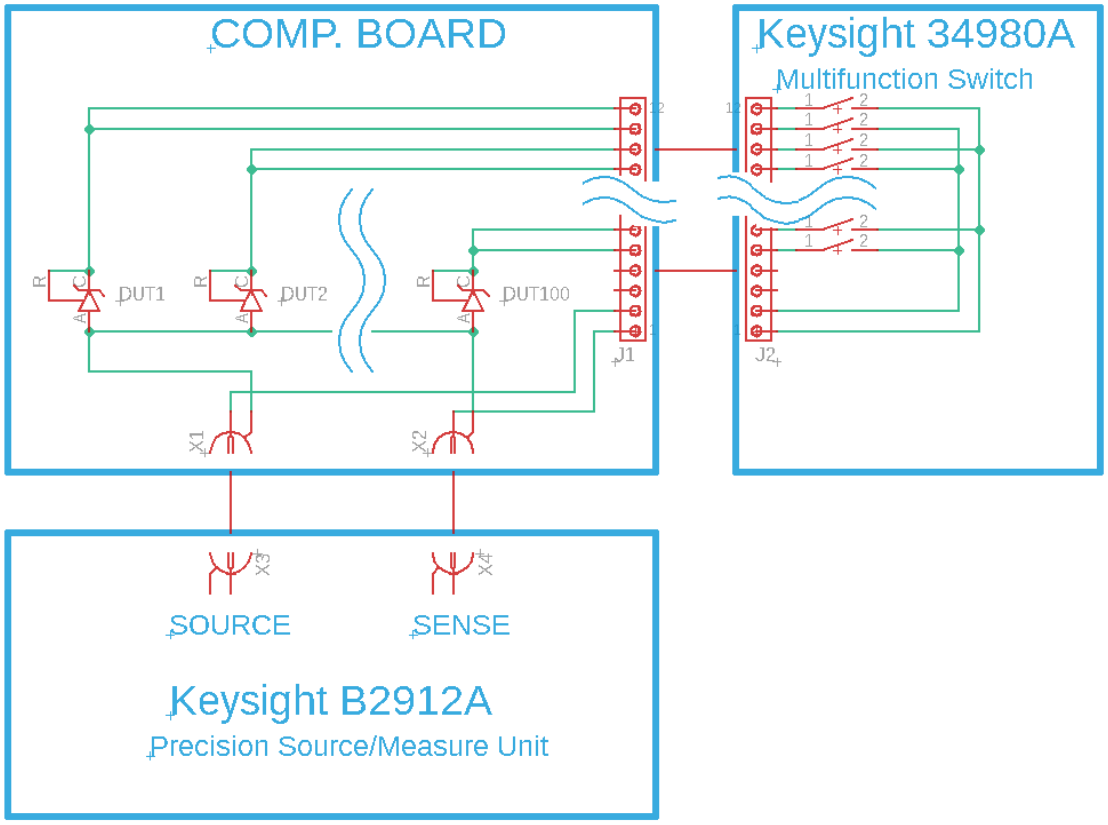


Figure 1: Simplified schematic of the overall test set-up

Four PCBs which were specially designed for this purpose could allow to accommodate both biased and unbiased components for this component and also other bandgap reference components at the same time on a 12 x 22 cm² PCB. This size of the boards limits the TID variation across board to less than 10%. Set-up pictures are provided in Annex B.

During each defined TID step a PC laptop was used to acquire the voltage (V_Z) as well as the input current (I_Z) of each of the samples from the source measure unit (SMU). The laptop time is synchronised to the time used for controlling the Co60 facility.

5.2. Test equipment

TEST EQUIPMENT	PARAMETER MEASURED
1 x Keysight B2912A 2412A Precision Source/Measure Unit (SMU)	Providing 6 different I_Z currents acc. to datasheet of the components: I_{min}, $0.8xI_{typ}$, I_{typ}, $3.14xI_{typ}$, $10xI_{typ}$, I_{max} V_{max} = 5.0 V
1 x Keysight 34980A Multifunction Switch	Switching through all up to 100 samples solder on one board.
1 x Laptop with LabView	Logging and saving the V_Z and I_Z measurements using an in-house VI.

6. TEST PARAMETERS

The following two parameters are measured:

PARAMETERS	SYMBOLS
Reverse Breakdown Voltage	V_Z
Reverse Current	I_Z

7. BIASING CONDITIONS

All biased samples are continuously biased with the typical value of I_Z according to the datasheet of each part type:

Table summarised the main biasing conditions

PART TYPE	Value	Unit
LT1634AIS8-2.5#PBF	10	µA

Table 2: Biasing conditions during irradiation

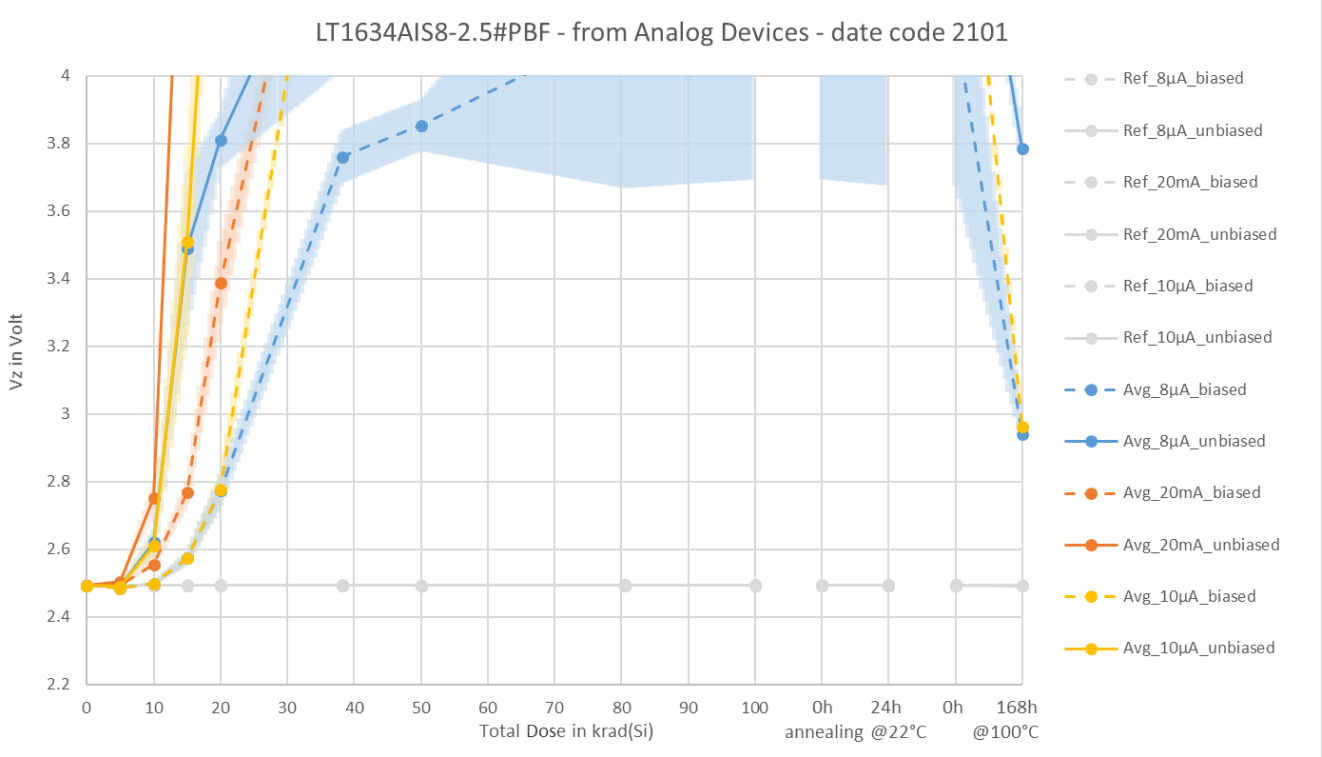
8. TID RESULTS

8.1. TID RESULTS - LT1634AIS8-2.5#PBF - from Analog Devices - date code 2101

LT1634AIS8-2.5#PBF - from Analog Devices - date code 2101 - @ I-min 8µA												
DUT No.	krad (Si)	0	5	10	15	20	38.2	50	80.5	100	Room Temp. annealing	100°C annealing
C10	unbiased	2.4932	2.4916	2.6269	3.5420	3.8433	5.0000	5.0000	5.0000	5.0000	5.0000	3.8129
C11		2.4931	2.4912	2.6176	3.4792	3.7711	3.9876	5.0000	5.0000	5.0000	5.0000	3.7464
C12		2.4933	2.4931	2.6699	3.7328	3.9109	5.0000	5.0000	5.0000	5.0000	5.0000	3.8627
C13		2.4934	2.4892	2.5600	3.1151	3.6928	3.9399	3.9949	5.0000	5.0000	5.0000	3.6951
C14		2.4925	2.4908	2.6297	3.5723	3.8404	5.0000	5.0000	5.0000	5.0000	5.0000	3.8066
C15	biased	2.4932	2.4834	2.4938	2.5622	2.7662	3.8429	3.9367	5.0000	5.0000	5.0000	2.9564
C16		2.4931	2.4842	2.5031	2.5874	2.7989	3.7764	3.8671	3.9679	3.9889	3.9734	2.9716
C17		2.4929	2.4849	2.5025	2.5923	2.8240	3.7824	3.8698	3.9667	3.9863	3.9703	2.9423
C18		2.4931	2.4848	2.5013	2.5778	2.7740	3.7714	3.8651	3.9685	3.9896	3.9738	2.9358
C19		2.4932	2.4843	2.4925	2.5470	2.7000	3.6310	3.7288	3.8344	3.8570	3.8419	2.8997
REF21	Ref unbiased	2.4926	2.4932	2.4931	2.4927	2.4928	2.4928	2.4928	2.4930	2.4933	2.4933	2.4923
REF71	Ref biased	2.4937	2.4940	2.4940	2.4937	2.4939	2.4937	2.4936	2.4940	2.4939	2.4943	2.4932

LT1634AIS8-2.5#PBF - from Analog Devices - date code 2101 - @ I-typ 10µA											Limit acc. DS: Vz = 2.5V ± 0.4% (2.49V – 2.51V)	
DUT No.	krad (Si)	0	5	10	15	20	38.2	50	80.5	100	Room Temp. annealing	100°C annealing
C10	unbiased	2.4932	2.4910	2.6173	3.5285	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C11		2.4932	2.4907	2.6093	3.4652	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C12		2.4933	2.4924	2.6567	3.8905	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C13		2.4935	2.4891	2.5563	3.0955	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C14		2.4926	2.4901	2.6198	3.5640	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C15	biased	2.4931	2.4833	2.4938	2.5623	2.7684	5.0000	5.0000	5.0000	5.0000	5.0000	2.9771
C16		2.4931	2.4840	2.5030	2.5873	2.8027	5.0000	5.0000	5.0000	5.0000	5.0000	2.9955
C17		2.4929	2.4848	2.5024	2.5923	2.8293	5.0000	5.0000	5.0000	5.0000	5.0000	2.9638
C18		2.4931	2.4848	2.5012	2.5777	2.7772	5.0000	5.0000	5.0000	5.0000	5.0000	2.9570
C19		2.4933	2.4844	2.4927	2.5476	2.7044	5.0000	5.0000	5.0000	5.0000	5.0000	2.9237
REF21	Ref unbiased	2.4926	2.4932	2.4931	2.4928	2.4929	2.4928	2.4928	2.4931	2.4933	2.4933	2.4923
REF71	Ref biased	2.4937	2.4940	2.4940	2.4937	2.4938	2.4937	2.4936	2.4940	2.4938	2.4943	2.4932

LT1634AIS8-2.5#PBF - from Analog Devices - date code 2101 - @ I-max 20mA												
DUT No.	krad (Si)	0	5	10	15	20	38.2	50	80.5	100	Room Temp. annealing	100°C annealing
C10	unbiased	2.4929	2.5053	2.7650	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C11		2.4928	2.5044	2.7477	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C12		2.4928	2.5062	2.8104	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C13		2.4930	2.5015	2.6687	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C14		2.4923	2.5046	2.7712	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C15	biased	2.4927	2.4927	2.5464	2.7475	3.3531	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C16		2.4927	2.4949	2.5631	2.7938	3.4611	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C17		2.4925	2.4949	2.5597	2.7954	3.5093	5.0000	5.0000	5.0000	5.0000	5.0000	3.9854
C18		2.4928	2.4958	2.5619	2.7834	3.4194	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C19		2.4929	2.4940	2.5425	2.7152	3.1946	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
REF21	Ref unbiased	2.4923	2.4929	2.4928	2.4925	2.4925	2.4925	2.4925	2.4928	2.4929	2.4930	2.4920
REF71	Ref biased	2.4934	2.4936	2.4936	2.4933	2.4935	2.4934	2.4933	2.4937	2.4934	2.4939	2.4928



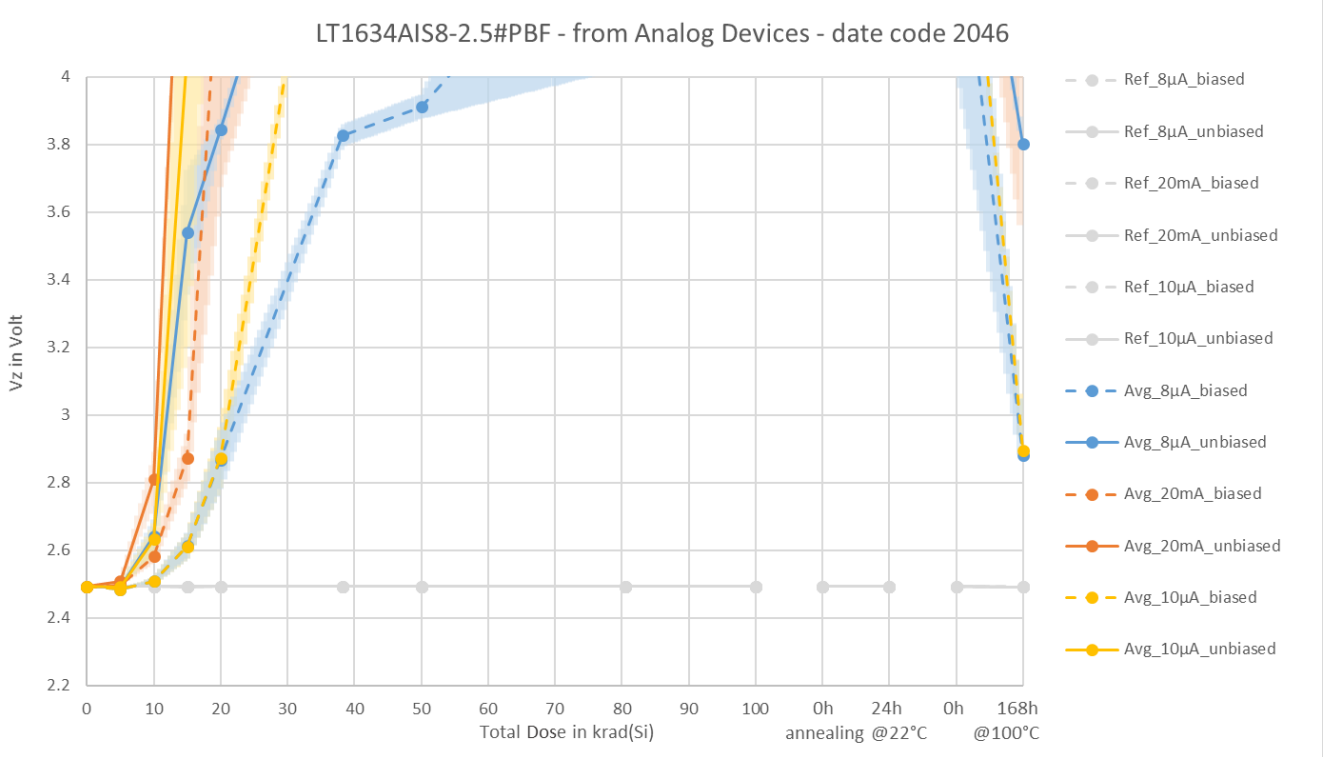
For all curves, which show an average over all measured samples, the coloured interval behind the curves represent +/- one standard deviation.

8.2. TID RESULTS - LT1634AIS8-2.5#PBF - from Analog Devices - date code 2046

LT1634AIS8-2.5#PBF - from Analog Devices - date code 2046 - @ I-min 8µA												
DUT No.	krad (Si)	0	5	10	15	20	38.2	50	80.5	100	Room Temp. annealing	100°C annealing
C20	unbiased	2.4929	2.4945	2.6872	3.6841	3.8587	5.0000	5.0000	5.0000	5.0000	5.0000	3.8098
C21		2.4926	2.4902	2.6048	3.4141	3.8225	5.0000	5.0000	5.0000	5.0000	5.0000	3.8056
C22		2.4932	2.4903	2.5847	3.2773	3.8098	5.0000	5.0000	5.0000	5.0000	5.0000	3.7841
C23		2.4922	2.4919	2.6401	3.6537	3.8853	5.0000	5.0000	5.0000	5.0000	5.0000	3.8293
C24		2.4926	2.4932	2.6947	3.6730	3.8425	5.0000	5.0000	5.0000	5.0000	5.0000	3.7746
C25	biased	2.4924	2.4828	2.4926	2.5559	2.7392	3.8195	3.9162	5.0000	5.0000	5.0000	2.8318
C26		2.4920	2.4855	2.5210	2.6596	2.9781	3.8125	3.8892	3.9794	3.9969	3.9805	2.9102
C27		2.4925	2.4856	2.5101	2.6165	2.8799	3.8332	3.9183	5.0000	5.0000	5.0000	2.9566
C28		2.4920	2.4846	2.5118	2.6263	2.8970	3.7894	3.8700	3.9632	3.9818	3.9646	2.8132
C29		2.4927	2.4852	2.5075	2.6032	2.8419	3.8763	3.9651	5.0000	5.0000	5.0000	2.8893
REF22	Ref unbiased	2.4924	2.4930	2.4929	2.4926	2.4926	2.4926	2.4926	2.4929	2.4930	2.4931	2.4921
REF72	Ref biased	2.4928	2.4930	2.4930	2.4927	2.4929	2.4928	2.4927	2.4931	2.4929	2.4933	2.4922

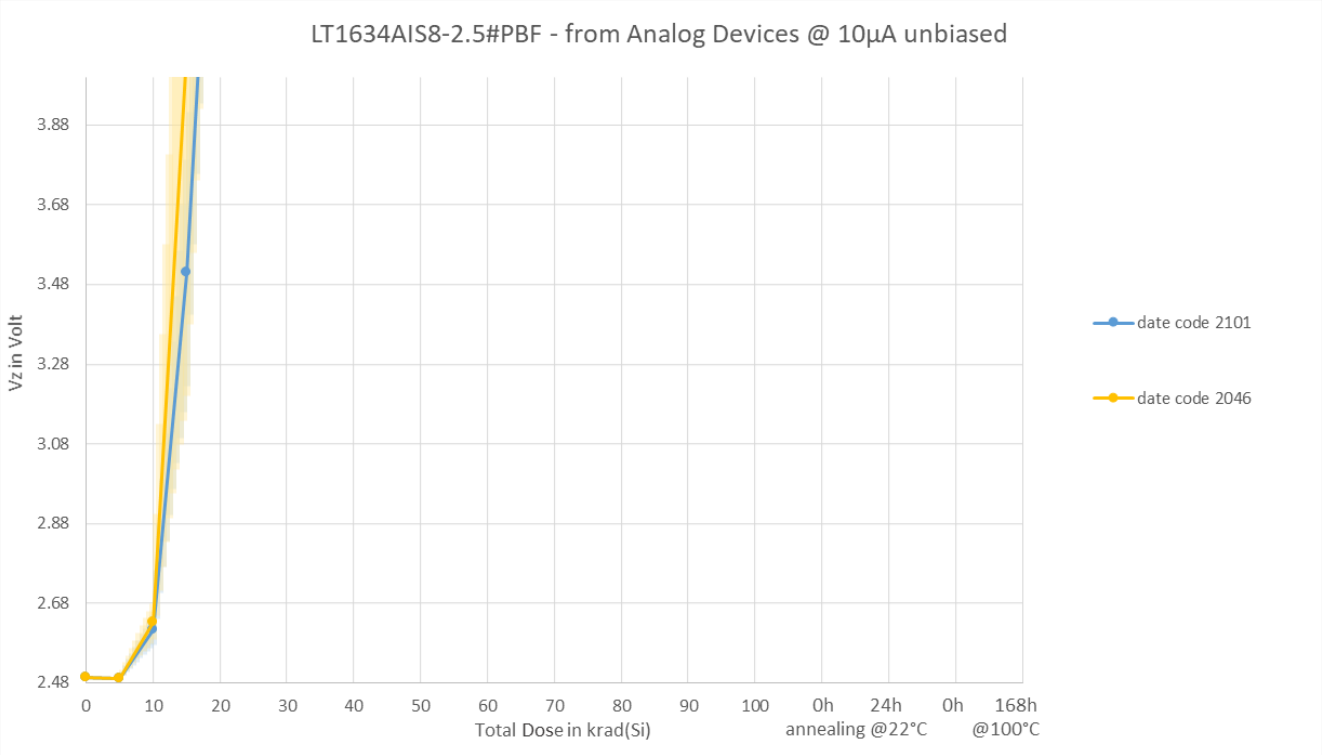
LT1634AIS8-2.5#PBF - from Analog Devices - date code 2046 - @ I-typ 10µA											Limit acc. DS: Vz = 2.5V ± 0.4% (2.49V – 2.51V)	
DUT No.	krad (Si)	0	5	10	15	20	38.2	50	80.5	100	Room Temp. annealing	100°C annealing
C20	unbiased	2.4930	2.4937	2.6749	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C21		2.4926	2.4898	2.5974	3.3972	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C22		2.4931	2.4898	2.5793	3.2569	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C23		2.4922	2.4914	2.6308	3.6748	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C24		2.4926	2.4927	2.6822	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C25	biased	2.4924	2.4827	2.4926	2.5558	2.7405	5.0000	5.0000	5.0000	5.0000	5.0000	2.8429
C26		2.4920	2.4853	2.5207	2.6591	2.9907	5.0000	5.0000	5.0000	5.0000	5.0000	2.9291
C27		2.4926	2.4855	2.5100	2.6160	2.8868	5.0000	5.0000	5.0000	5.0000	5.0000	2.9795
C28		2.4920	2.4845	2.5117	2.6261	2.9050	5.0000	5.0000	5.0000	5.0000	5.0000	2.8251
C29		2.4926	2.4850	2.5074	2.6023	2.8455	5.0000	5.0000	5.0000	5.0000	5.0000	2.9032
REF22	Ref unbiased	2.4924	2.4930	2.4928	2.4926	2.4926	2.4926	2.4926	2.4929	2.4931	2.4931	2.4920
REF72	Ref biased	2.4928	2.4931	2.4931	2.4927	2.4929	2.4928	2.4927	2.4931	2.4929	2.4933	2.4922

LT1634AIS8-2.5#PBF - from Analog Devices - date code 2046 - @ I-max 20mA												
DUT No.	krad (Si)	0	5	10	15	20	38.2	50	80.5	100	Room Temp. annealing	100°C annealing
C20	unbiased	2.4926	2.5127	2.8841	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C21		2.4922	2.5050	2.7485	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C22		2.4929	2.5044	2.7173	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C23		2.4920	2.5075	2.7989	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C24		2.4923	2.5117	2.8998	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C25	biased	2.4920	2.4940	2.5527	2.7620	3.3798	5.0000	5.0000	5.0000	5.0000	5.0000	3.6108
C26		2.4917	2.4985	2.5990	2.9475	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	3.9276
C27		2.4922	2.4992	2.5874	2.8929	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
C28		2.4917	2.4977	2.5882	2.9026	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000	3.5413
C29		2.4924	2.4987	2.5821	2.8636	3.8589	5.0000	5.0000	5.0000	5.0000	5.0000	5.0000
REF22	Ref unbiased	2.4921	2.4927	2.4925	2.4923	2.4924	2.4923	2.4924	2.4926	2.4928	2.4929	2.4917
REF72	Ref biased	2.4926	2.4929	2.4928	2.4925	2.4927	2.4926	2.4925	2.4929	2.4926	2.4931	2.4920



8.1. Comparison Manufacturer and Date Code

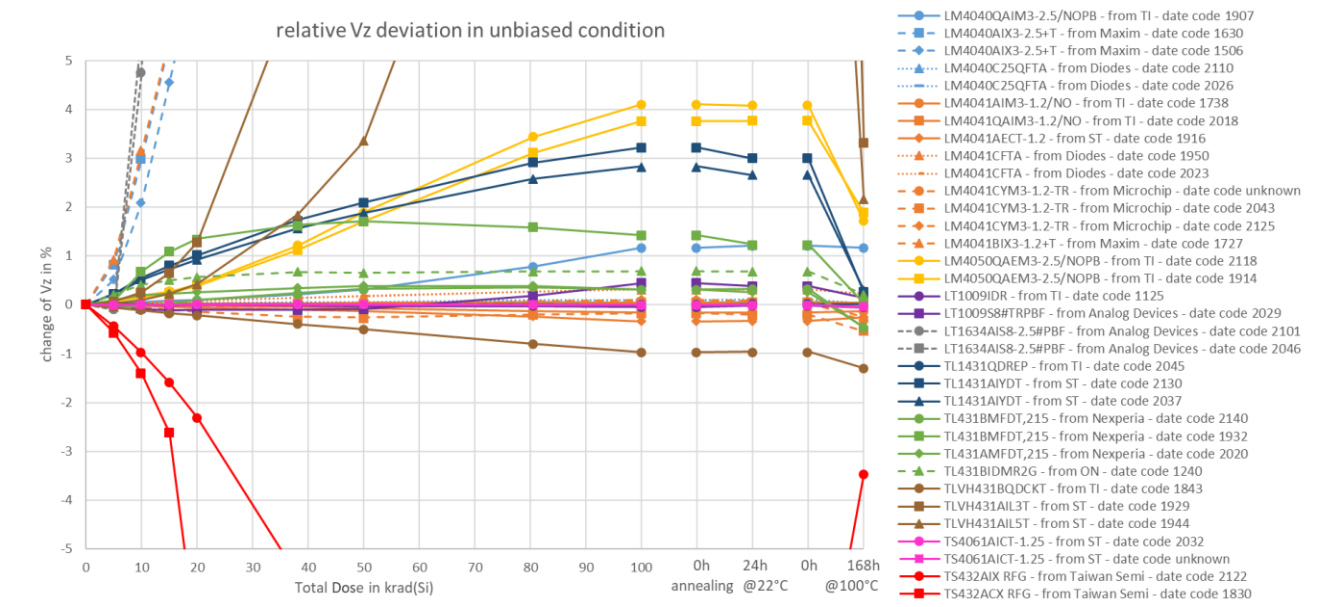
The following graph shows the different behaviour of all measured LT11634 voltage references with different date code.

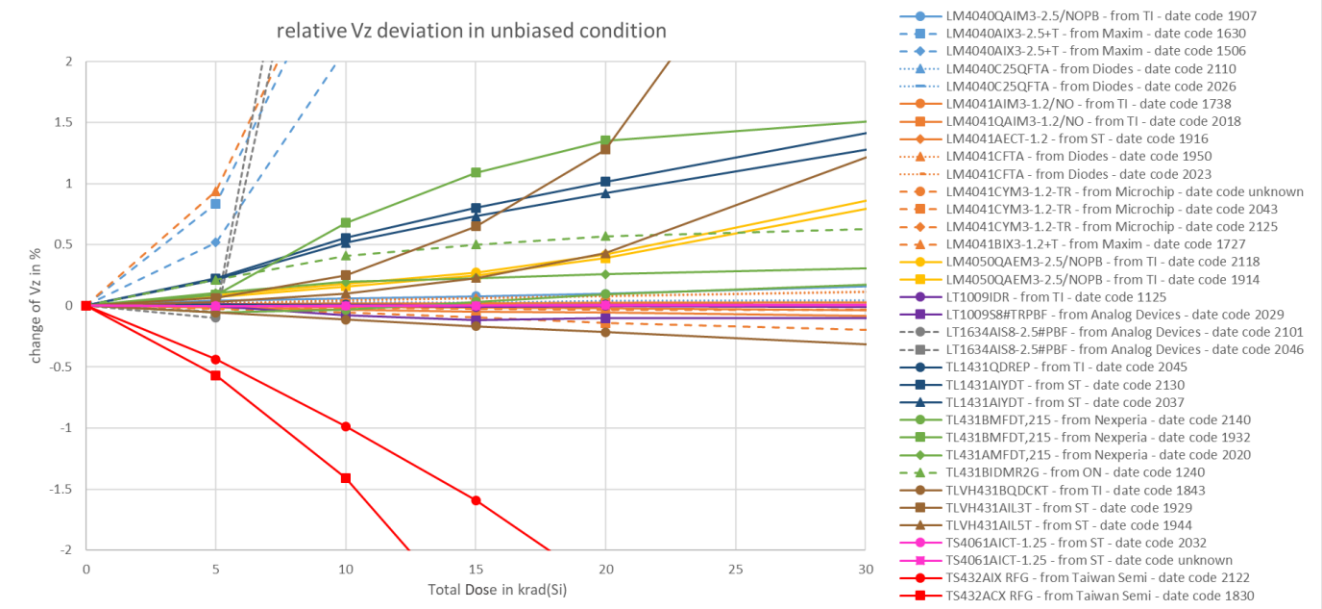


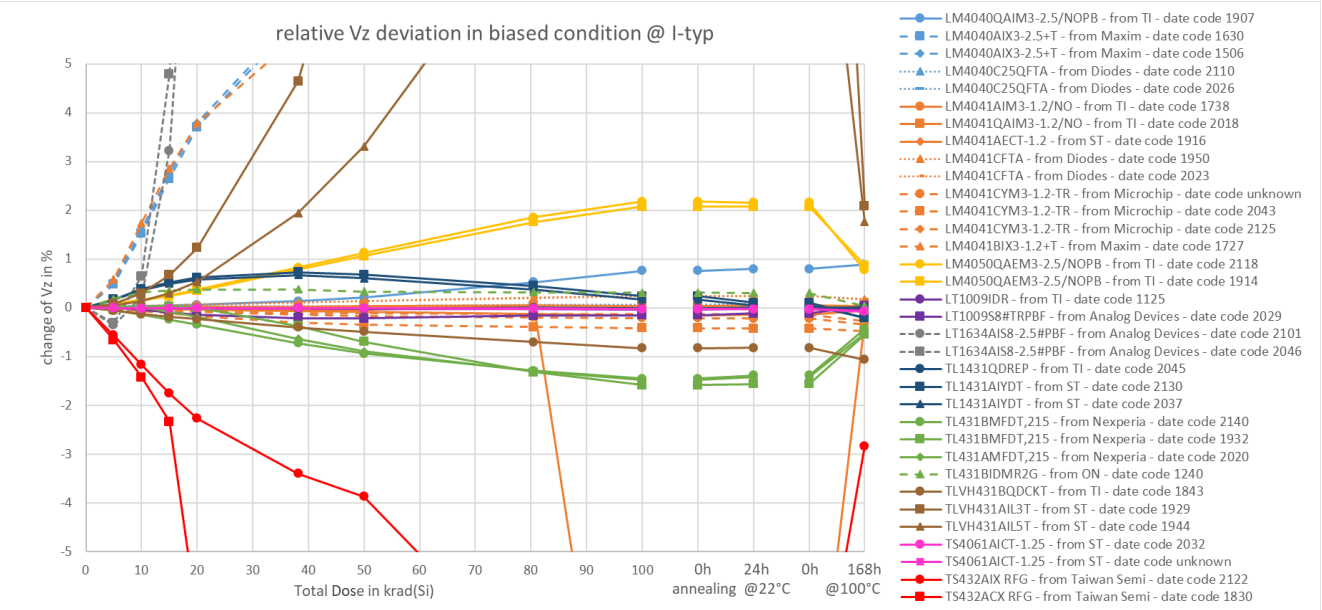
All curves plotted show the average value of all unbiased tested samples (worst case) and the interval behind the curves represent +/- one standard deviation.

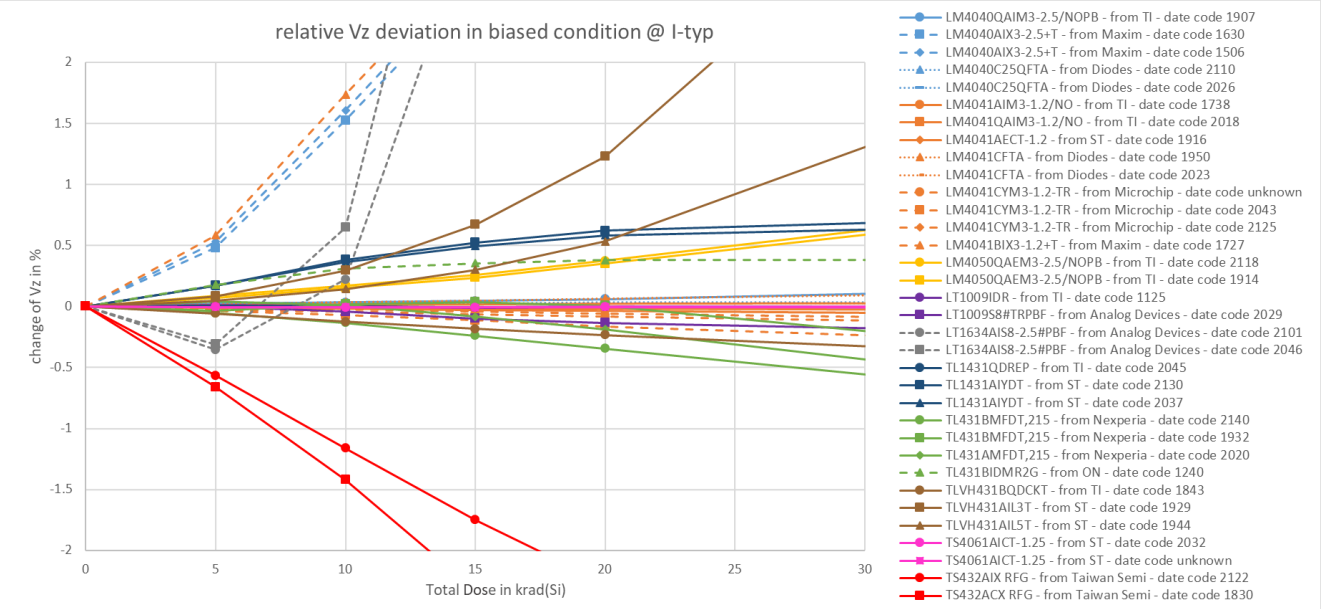
8.2. Comparison with other tested Bandgap References

The following four graphs show the results of the LT1634 Bandgap Voltage References compared to different Bandgap References part types, which were tested at the same time with the same test setup than the LT1634. Additional information on these tests is provided in the Radiation Test Summary [RD02].






relative Vz deviation in biased condition @ I-typ
change of Vz in %
Total Dose in krad(Si)
0h
24h
0h
168h
annealing @22°C
@100°C
LM4040QAIM3-2.5/NOPB - from TI - date code 1907
LM4040AIX3-2.5+T - from Maxim - date code 1630
LM4040AIX3-2.5+T - from Maxim - date code 1506
LM4040C25QFTA - from Diodes - date code 2110
LM4040C25QFTA - from Diodes - date code 2026
LM4041AIM3-1.2/NO - from TI - date code 1738
LM4041QAIM3-1.2/NO - from TI - date code 2018
LM4041AECT-1.2 - from ST - date code 1916
LM4041CFTA - from Diodes - date code 1950
LM4041CFTA - from Diodes - date code 2023
LM4041CYM3-1.2-TR - from Microchip - date code unknown
LM4041CYM3-1.2-TR - from Microchip - date code 2043
LM4041CYM3-1.2-TR - from Microchip - date code 2125
LM4041BIX3-1.2+T - from Maxim - date code 1727
LM4050QAEM3-2.5/NOPB - from TI - date code 2118
LM4050QAEM3-2.5/NOPB - from TI - date code 1914
LT1009IDR - from TI - date code 1125
LT1009S8#TRPBF - from Analog Devices - date code 2029
LT1634AIS8-2.5#PBF - from Analog Devices - date code 2101
LT1634AIS8-2.5#PBF - from Analog Devices - date code 2046
TL1431QDREP - from TI - date code 2045
TL1431AIYDT - from ST - date code 2130
TL1431AIYDT - from ST - date code 2037
TL431BMFDT,215 - from Nexperia - date code 2140
TL431BMFDT,215 - from Nexperia - date code 1932
TL431AMFDT,215 - from Nexperia - date code 2020
TL431BIDMR2G - from ON - date code 1240
TLVH431BQDCKT - from TI - date code 1843
TLVH431AIL3T - from ST - date code 1929
TLVH431AIL5T - from ST - date code 1944
TS4061AICT-1.25 - from ST - date code 2032
TS4061AICT-1.25 - from ST - date code unknown
TS432AIX RFG - from Taiwan Semi - date code 2122
TS432ACX RFG - from Taiwan Semi - date code 1830


relative Vz deviation in biased condition @ I-typ
change of Vz in %
Total Dose in krad(Si)
LM4040QAIM3-2.5/NOPB - from TI - date code 1907
LM4040AIX3-2.5+T - from Maxim - date code 1630
LM4040AIX3-2.5+T - from Maxim - date code 1506
LM4040C25QFTA - from Diodes - date code 2110
LM4040C25QFTA - from Diodes - date code 2026
LM4041AIM3-1.2/NO - from TI - date code 1738
LM4041QAIM3-1.2/NO - from TI - date code 2018
LM4041AECT-1.2 - from ST - date code 1916
LM4041CFTA - from Diodes - date code 1950
LM4041CFTA - from Diodes - date code 2023
LM4041CYM3-1.2-TR - from Microchip - date code unknown
LM4041CYM3-1.2-TR - from Microchip - date code 2043
LM4041CYM3-1.2-TR - from Microchip - date code 2125
LM4041BIX3-1.2+T - from Maxim - date code 1727
LM4050QAEM3-2.5/NOPB - from TI - date code 2118
LM4050QAEM3-2.5/NOPB - from TI - date code 1914
LT1009IDR - from TI - date code 1125
LT1009S8#TRPBF - from Analog Devices - date code 2029
LT1634AIS8-2.5#PBF - from Analog Devices - date code 2101
LT1634AIS8-2.5#PBF - from Analog Devices - date code 2046
TL1431QDREP - from TI - date code 2045
TL1431AIYDT - from ST - date code 2130
TL1431AIYDT - from ST - date code 2037
TL431BMFDT,215 - from Nexperia - date code 2140
TL431BMFDT,215 - from Nexperia - date code 1932
TL431AMFDT,215 - from Nexperia - date code 2020
TL431BIDMR2G - from ON - date code 1240
TLVH431BQDCKT - from TI - date code 1843
TLVH431AIL3T - from ST - date code 1929
TLVH431AIL5T - from ST - date code 1944
TS4061AICT-1.25 - from ST - date code 2032
TS4061AICT-1.25 - from ST - date code unknown
TS432AIX RFG - from Taiwan Semi - date code 2122
TS432ACX RFG - from Taiwan Semi - date code 1830

9. CONCLUSION

All tested components with different date codes reached a deviation outside specification limits at a dose around below 10krad.

The deviation of tested components from the two different date codes show a simillar behaviour in respect of TID effects.

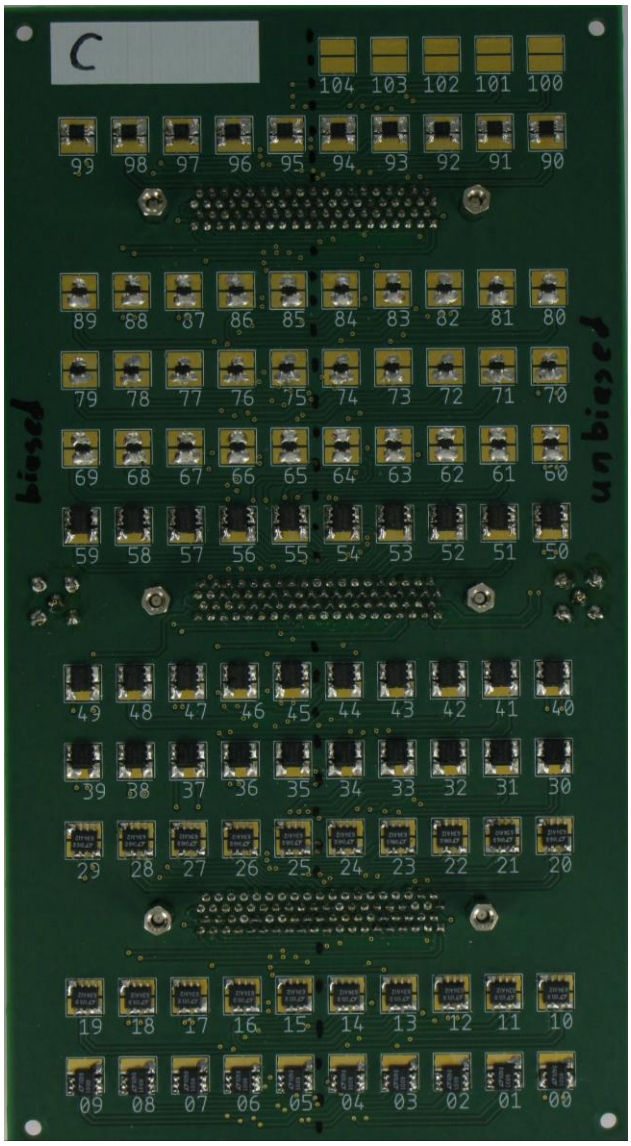
In general, a higher deviation was found for the unbiased samples.

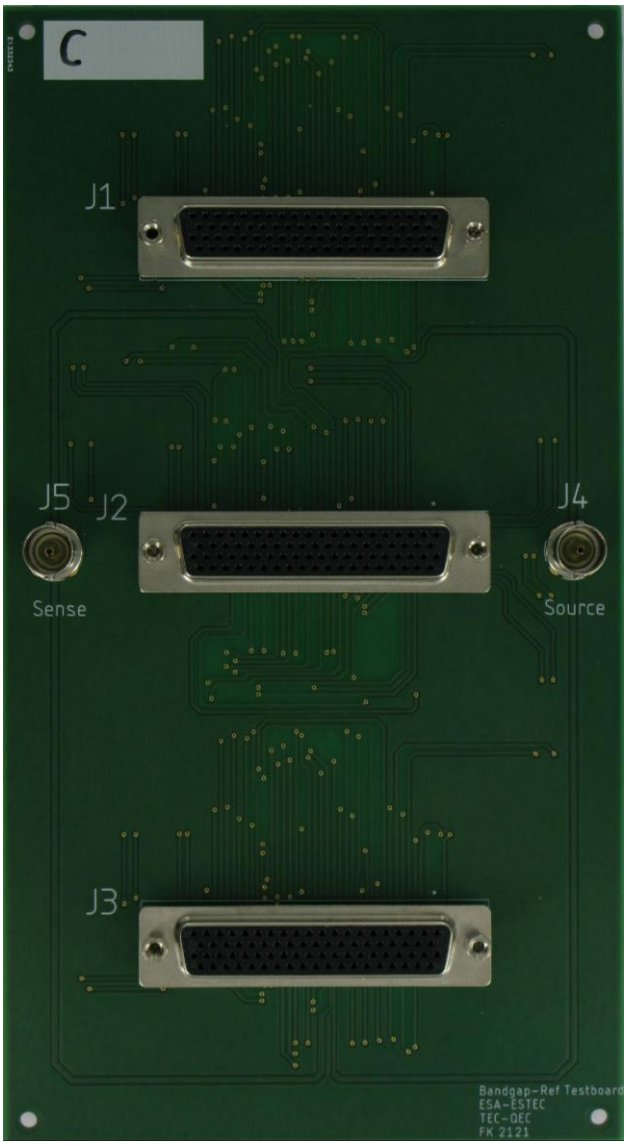
ANNEX A – DATASHEET

Part Type	Manufacturer	Link to Datasheet
LT1634AIS8-2.5#PBF	Analog Devices	https://www.analog.com/media/en/technical-documentation/data-sheets/1634ff.pdf

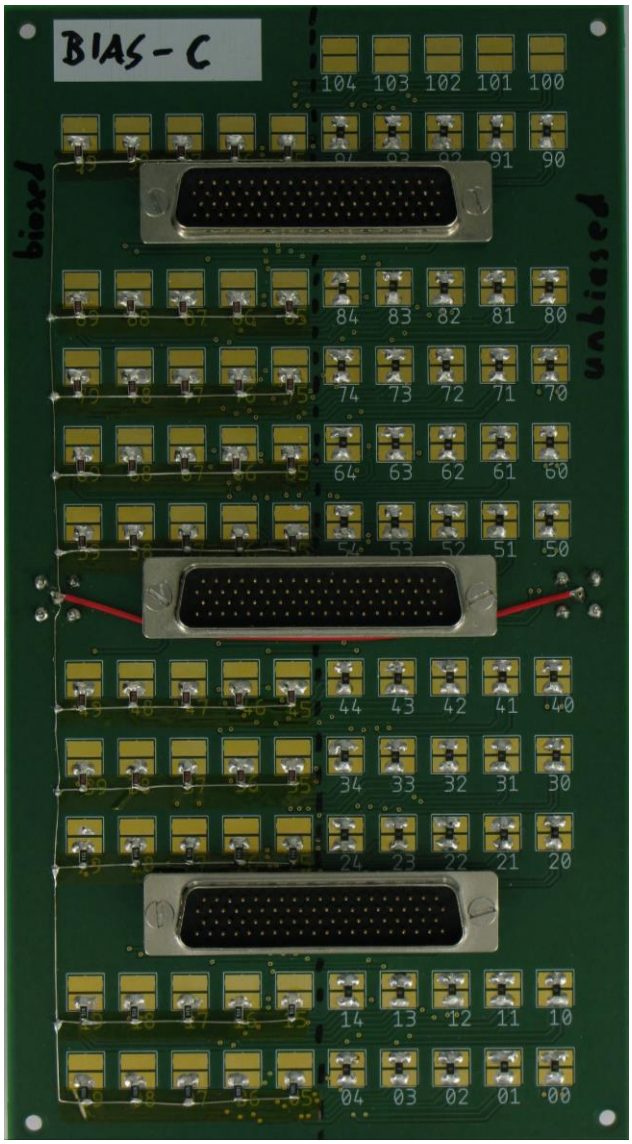
ANNEX B – SET-UP

Test board front- and backside with the LT1634 on position 10 to 29 on board C:

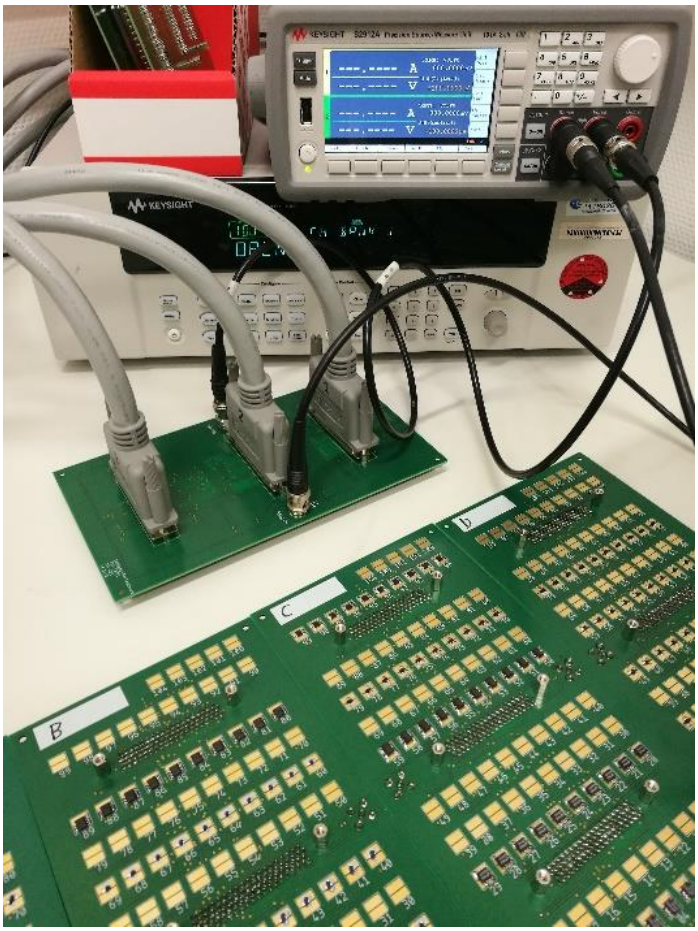




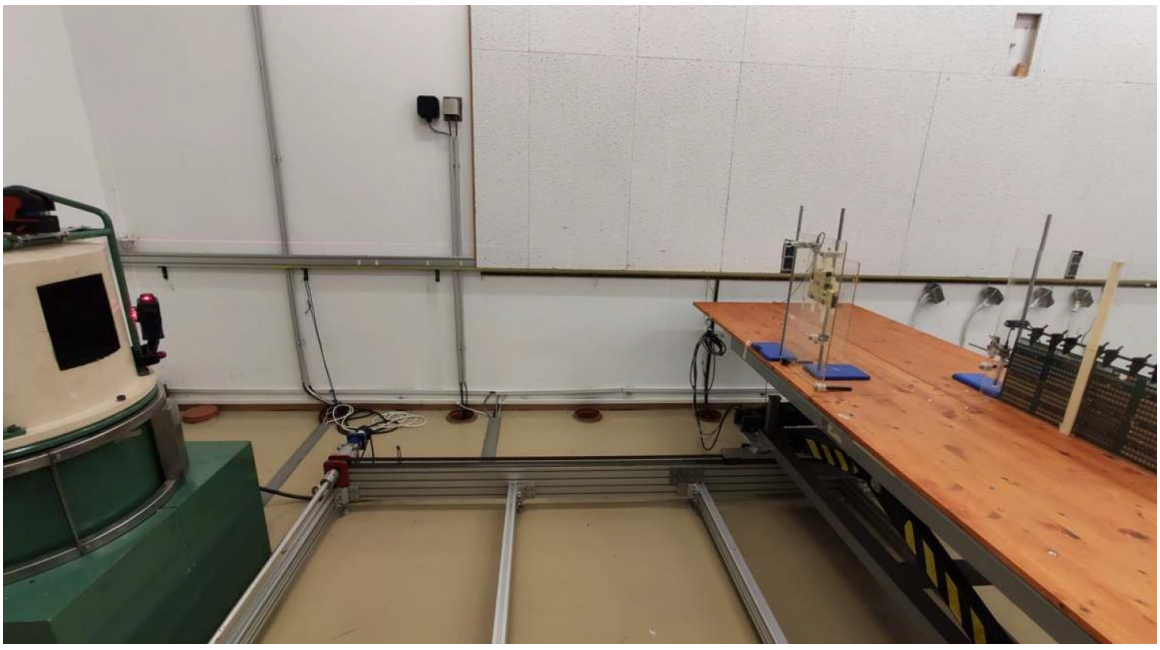
Biasing board front- and backside with the biasing resistors on it:

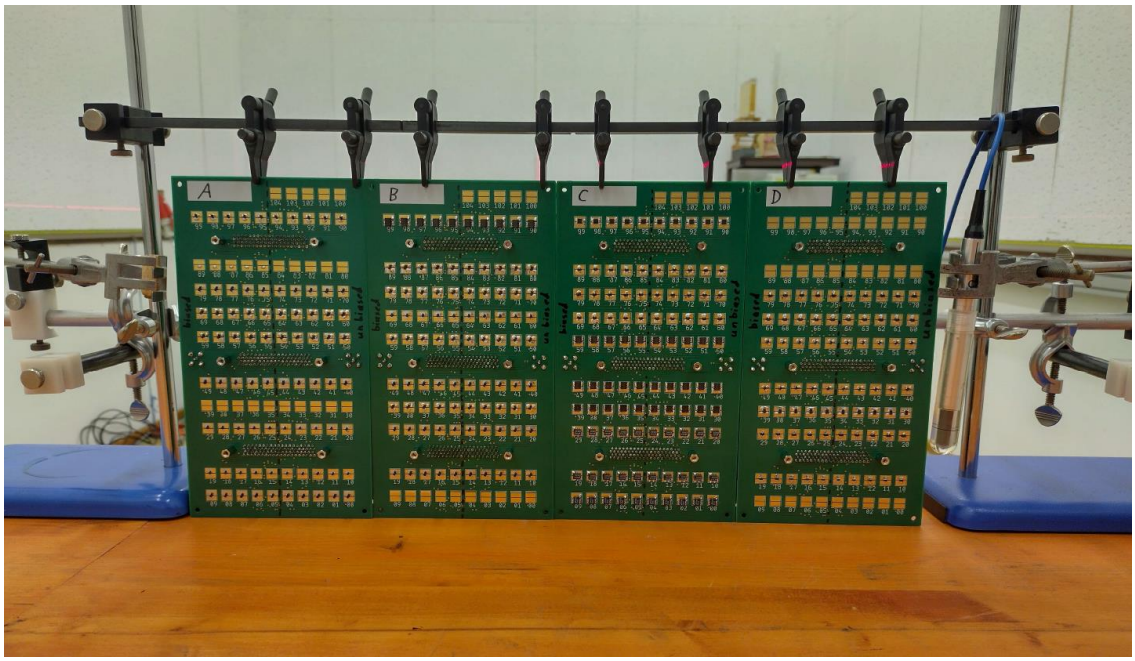


Measurement setup with the cable connection from the Test Board to the Switching Matrix and the Source Measure Unit:



Position of the boards inside the Co60 irradiation chamber:





ANNEX C – RADIATION TEST SUMMARY – IRRADIATION STEPS

Irr. Run	*Start Date & Time (CET)*	*End Date & Time (CET)*	*Total Ionising Dose (water)*	*Dose Rate (water)*
1	24-01-2022 18:11:39	25-01-2022 13:37:10	55.69 Gy	2.867 Gy/h
2	25-01-2022 15:13:42	26-01-2022 11:52:43	55.67 Gy	2.696 Gy/h
3	26-01-2022 13:30:18	27-01-2022 10:16:45	55.68 Gy	2.680 Gy/h
4	27-01-2022 12:11:47	28-01-2022 08:55:59	55.68 Gy	2.685 Gy/h
5	28-01-2022 10:31:55	31-01-2022 09:30:00	202.3 Gy	2.851 Gy/h
6	31-01-2022 11:18:44	02-02-2022 09:21:12	131.8 Gy	2.863 Gy/h
7	02-02-2022 11:05:44	07-02-2022 09:55:08	339.6 Gy	2.858 Gy/h
8	07-02-2022 11:41:36	10-02-2022 15:46:14	217.1 Gy	2.854 Gy/h
		Total	*1.114 kGy*	

Note: *The uncertainty budgets (according to TEC-QEC/PR001 section 12) are: 4.2 % (k=2) for absorbed dose to water and 4.4% (k=2) for absorbed dose rate to water*

	units	*Min.*	*Max.*	Time-weighted Average
Temperature	°C	20.9	21.2	20.93
Pressure	mbar	996.6	1034.5	1019.01
Relative Humidity	%	47.1	54	51.45

Dosimeter position relative to ^{60}Co source		
X	cm	36.5
Y	cm	292
Z	cm	-21

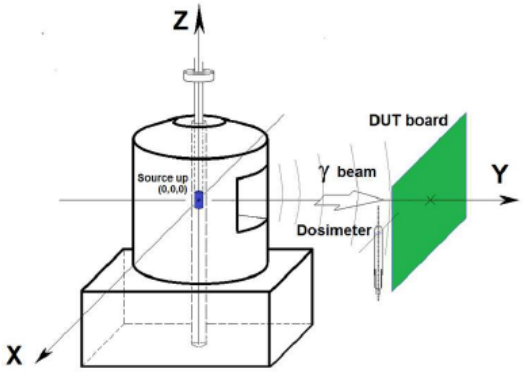


Figure 1 Co-60 irradiator head and board positioning sketch

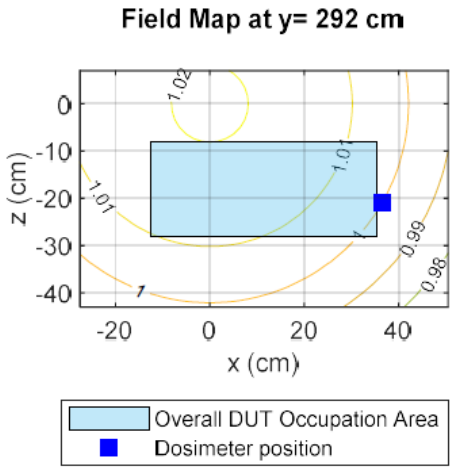


Figure 2: Qualitative indication of dose rate distribution normalized to dosemeter readings. Axes origin located at source centre. Graphs for information only, of the run with highest dose rate.